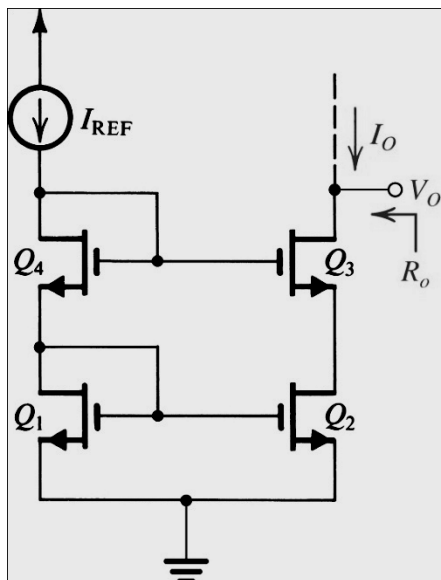


Examples #3

1. For a cascade MOS mirror utilizing devices with $V_t=0.5\text{V}$, $\mu_n C_{ox}=387\mu\text{A}/\text{V}^2$, $W/L=3.6\mu\text{m}/0.36\mu\text{m}$, $V_A'=10\text{V}/\mu\text{m}$, and $I_{REF}=100\mu\text{A}$. Find the minimum voltage required at the output and the output resistance.



$$I_{D1} = I_{D2} = I_{D3} = I_{D4} = I_{REF} = 100 \mu\text{A}$$

$$\text{Since } I_D = \frac{1}{2} \mu_n C_{ox} \left(\frac{W}{L}\right) V_{OV}^2$$

$$V_{OV} = \sqrt{\frac{2I_D}{\mu_n C_{ox} \left(\frac{W}{L}\right)}} = \sqrt{\frac{2(100 \mu\text{A})}{(387 \mu\text{A}/\text{V}^2) \left(\frac{3.6}{0.36}\right)}}$$

$$= 0.23 \text{ V}$$

The minimum output voltage is

$$V_{\text{min}} + 2V_{OV} = 0.5 \text{ V} + 2(0.23 \text{ V}) = 0.96 \text{ V}$$

To obtain the output resistance, R_o , we need g_{m3} .

$$g_{m3} = \frac{I_{D3}}{V_{OV}/2} = \frac{2(0.1 \text{ mA})}{0.23 \text{ V}} = 0.87 \text{ mA/V}$$

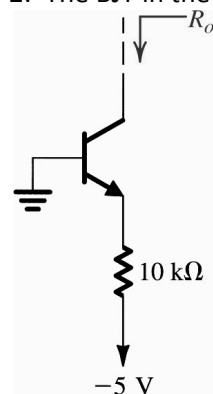
$$r_{o2} = r_{o3} = \frac{V_A'(L)}{I_D} = \frac{(5 \text{ V}/\mu\text{m})(0.36 \mu\text{m})}{0.1 \text{ mA}}$$

$$= 18 \text{ k}\Omega. \text{ From eq. (7.77)}$$

$$R_o \approx g_{m3} r_{o3} r_{o2} = (0.87 \text{ mA/V})(18 \text{ k}\Omega)^2$$

$$= 282 \text{ k}\Omega$$

2. The BJT in the circuit below has $v_{BE}=0.7\text{V}$, $\beta=100$ and $V_A=50\text{V}$. Find R_o .



$$I_E = \frac{V_E - V_{EE}}{R_E} = \frac{-0.7 - (-5)}{10 \text{ k}\Omega} = 0.43 \text{ mA}$$

$$g_m = \frac{I_C}{V_r} = \frac{0.43 \text{ mA}}{25 \text{ mV}} = 17.2 \text{ mA/V}$$

$$r_o = \frac{V_A}{I_C} = \frac{50 \text{ V}}{0.43 \text{ mA}} = 116.3 \text{ k}\Omega$$

$$r_\pi = \frac{\beta}{g_m} = \frac{100}{17.2 \text{ mA/V}} = 5.8 \text{ k}\Omega$$

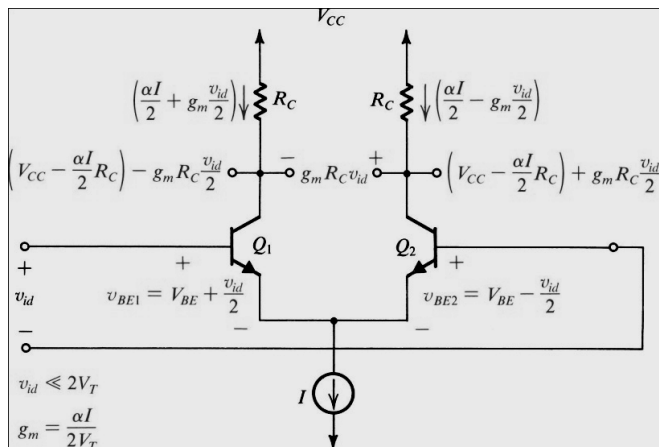
$$R_o = r_o [1 + g_m (R_E \parallel r_\pi)]$$

$$R_o = (116.3 \text{ k}\Omega)$$

$$[1 + (17.2 \text{ mA/V})(10 \text{ k}\Omega \parallel 5.8 \text{ k}\Omega)] = 7.46 \text{ M}\Omega$$

Examples #3

3. Design the basic BJT differential amplifier shown below to provide a differential input resistance of at least 10kΩ and a differential voltage gain of 100 V/V. The transistor β is specified to be at least 100. The available positive power supply is 5V.



$$R_{id} \geq 10 \text{ k}\Omega \quad A_d = 100 \text{ V/V} \quad V_{CC} = 5 \text{ V}$$

$$R_{id} = 10^4 = 2r_{\pi} = 2 \times \frac{\beta}{g_m}$$

$$g_m = \frac{2\beta}{R_{id}} = 20 \text{ mA/V}$$

$$g_m = \frac{I_C}{V_T}$$

$$I_C = g_m V_T = 20 \text{ mA/V} \cdot 25 \text{ mV} = 0.5 \text{ mA}$$

$$I = 2I_C = 1 \text{ mA}$$

$$\text{Eqn 8.93 } A_d = g_m R_C$$

$$R_C = \frac{A_d}{g_m} = \frac{100}{20 \text{ mA/V}} = 5 \text{ k}\Omega$$

Examples #3

4. A BJT differential amplifier is biased from a 1mA constant-current source and includes a 200Ω resistor in each emitter. The collectors are connect to V_{CC} via 12kΩ resistors. A differential input signal of 0.1V is applied between the two bases.

- Find the signal current in the emitters (i_o) and the signal voltage v_{be} for each BJT.
- What is the total emitter current in each BJT?
- What is the signal voltage at each collector? Assume $\alpha=1$.
- What is the voltage gain realized when the output is taken between the two collectors?

$$I = 1\text{mA} \quad R_E = 200 \Omega \quad R_C = 12 \text{ k}\Omega$$

$$V_{id} = 100 \text{ mV}$$

$$r_e = \frac{V_T}{I_E} = \frac{25 \text{ mV}}{1 \text{ mA} / 2} = 50 \Omega$$

$$(a) \quad i_e = \frac{V_{id}}{2(r_e + R_E)} = \frac{100 \text{ mV}}{2(250 \Omega)} = 0.2 \text{ mA}$$

$$V_{be} = \frac{r_e}{r_e + R_E} \left(\frac{V_{id}}{2} \right) = 10 \text{ mV}$$

(b)

$$i_{E1} = \frac{I}{2} + i_e = 0.5 \text{ mA} + 0.2 \text{ mA} = 0.7 \text{ mA}$$

$$i_{E2} = \frac{I}{2} - i_e = 0.5 \text{ mA} - 0.2 \text{ mA} = 0.3 \text{ mA}$$

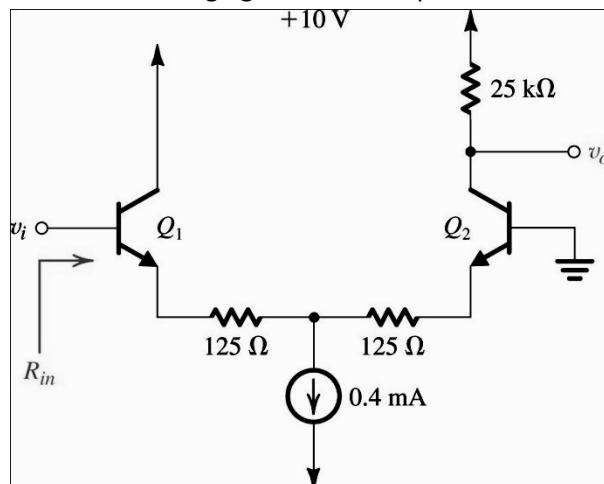
(c)

$$V_{C1} = -i_C R_C \approx -i_e \cdot R_C = -0.2 \text{ mA} \cdot 12 \text{ k}\Omega = -2.4 \text{ V}$$

$$V_{C2} = +i_C R_C \approx i_e \cdot R_C = 0.2 \text{ mA} \cdot 12 \text{ k}\Omega = +2.4 \text{ V}$$

$$(d) \quad A_d = V_{od} / V_{id} = \frac{4.8 \text{ V}}{100 \text{ mV}} = 48 \text{ V/V}$$

5. Find the voltage gain and the input resistance of the amplifier shown below assuming $\beta=100$.



$$\frac{v_o}{v_i} = \frac{\alpha R_{C2}}{(2r_e + 2R_e)}$$

$$r_e = \frac{V_T}{I_E} = \frac{25 \text{ mV}}{0.4 \text{ mA} / 2} = 125 \Omega$$

Assuming $\alpha \approx 1$,

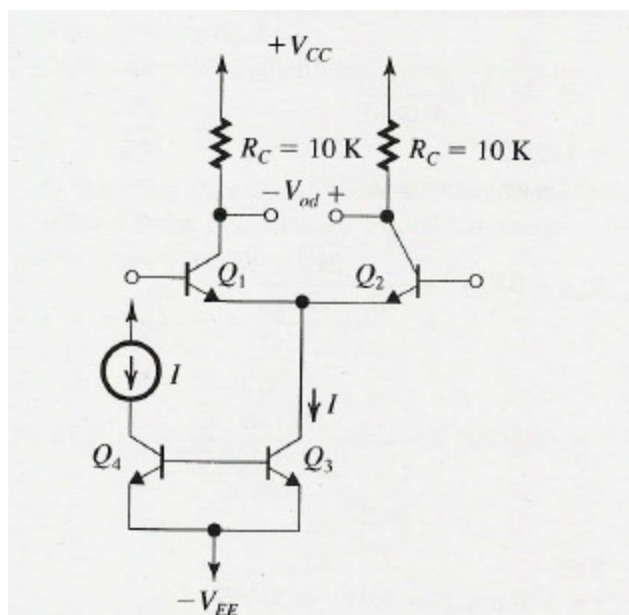
$$\frac{v_o}{v_i} \approx \frac{25 \text{ k}}{(2)(125) + 2(125)} = 50 \text{ V/V}$$

$$R_i = (\beta + 1)(2r_e + 2R_e) = (101)[2(125) + 2(125)] = 50.5 \text{ k}\Omega$$

Examples #3

6. A bipolar differential amplifier with $I=0.5\text{mA}$ utilizes transistors for which $V_A=10\text{V}$ and $\beta=100$ and $R_C=10\text{k}\Omega$.

- the differential gain
- the common mode gain and the CMRR if the bias current I is generated using a simple current mirror.
- the common mode gain and the CMRR if the bias current I is generated using a Wilson mirror.



Equivalent

$$R_{EE} = r_{o3} = \frac{V_A}{I} = \frac{10 \text{ V}}{0.5 \text{ mA}} = 20 \text{ k}\Omega$$

$$r_{e2} = r_{e1} = r_e = \frac{V_T}{I/2} = \frac{25 \text{ mV}}{0.5 \text{ mA}/2} = 100 \Omega$$

$$\text{Since } \alpha = \frac{\beta}{\beta + 1} = \frac{100}{101} \approx 1,$$

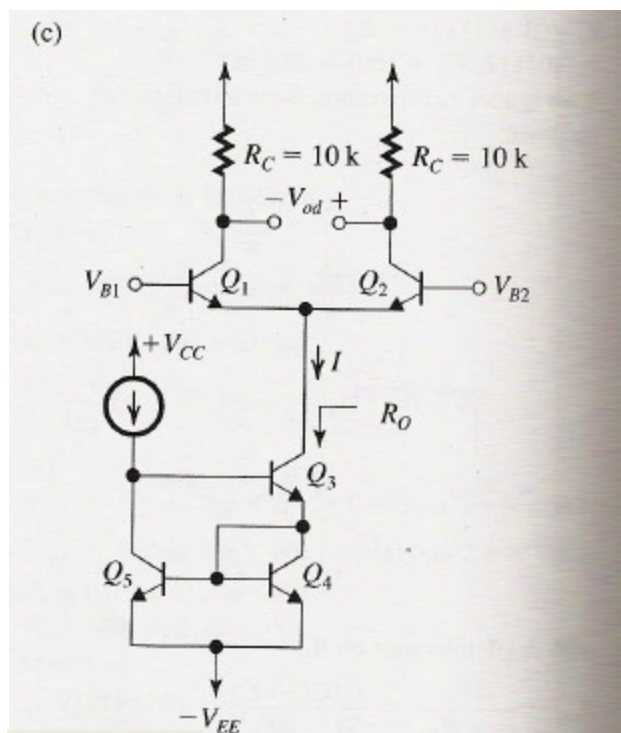
$$A_d \approx \frac{R_C}{r_e} = \frac{10 \text{ k}}{0.1 \text{ k}} = 100 \text{ V/V}$$

$$(b) A_{cm} \approx \frac{\alpha \Delta R_C}{2R_{EE} + r_e} = \frac{(0.02)(10 \text{ k})}{2(20 \text{ k}) + 0.1 \text{ k}}$$

$$= 0.00499 \text{ V/V}$$

$$\text{CMRR(dB)} = 20 \log_{10} \left| \frac{A_d}{A_{cm}} \right| = 20 \log_{10} \left| \frac{100}{0.00499} \right|$$

$$= 86 \text{ dB}$$



$$R_o \approx \frac{1}{2} \beta_3 r_{o3}$$

$$R_o \approx \frac{1}{2} (100)(20 \text{ k}) = 1 \text{ M}\Omega$$

$$A_{cm} \approx \frac{\Delta R_C}{2R_o + r_e} \approx$$

$$\frac{(0.02)(10 \text{ k})}{2(1 \text{ m}) + 0.1 \text{ k}} = 0.0001 \text{ V/V}$$

$$\text{CMRR(dB)} = 20 \log_{10} \left| \frac{A_d}{A_{cm}} \right| = 20 \log_{10} \left| \frac{100}{0.0001} \right|$$

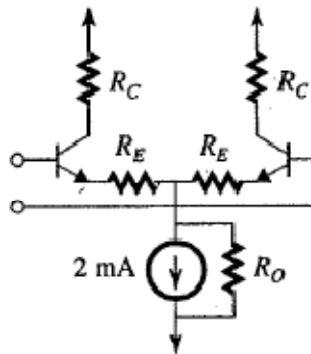
$$= 120 \text{ dB}$$

Examples #3

7. Design a BJT differential amplifier that provides two single-ended outputs (at the collectors). The amplifier is to have a differential gain (to each of the two outputs) of at least 100 V/V, a differential input resistance $\geq 10\text{k}\Omega$ and a common mode gain (to each of the two outputs) no greater than 0.1 V/V. Use a 2mA current source for biasing. Give the complete circuit with component values and suitable power supplies that allow for $\pm 2\text{V}$ swing at each collector. Specify the minimum value that the output resistance of the bias current source must have. The BJTs available have $\beta \geq 100$. What is the value of the input common mode resistance when the bias source has the lowest acceptable resistance?

At $I_C = 1\text{ mA}$, $r_e = 25\ \Omega$
 $R_{id} = (\beta + 1) 2r_e = 5.05\ \text{k}\Omega < 10\ \text{K}$
 \Rightarrow need emitter resistors

In this case:



$$R_{id} = (\beta + 1) (2r_e + 2R_E) = 10\ \text{k}\Omega$$

$$A_d = 100 = \frac{R_C}{2(R_E + r_e)}$$

$$\Rightarrow R_C = 10\ \text{K}$$

$$A_{cm} = 0.1 \geq \frac{R_C}{2R_O + R_E + r_e}$$

$$\Rightarrow R_O \geq 50\ \text{k}\Omega$$

For ± 2 swing $V_{c1} = V_{c2}$

$$= V_{CC} - \frac{I}{2} R_C = 2$$

$$\Rightarrow V_{CC} = 2 + 10^{-3} \times 10^4 = 12\ \text{V}$$

Choose $V_{CC} = \pm 15\ \text{V}$ although 12 V is ok.

$$2R_{icm} = (\beta + 1) (2R_O + R_E + r_e)$$

$$\Rightarrow R_{icm} = 5\ \text{M}\Omega$$